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# ne<mark>x</mark>peria

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Kind regards,

Team Nexperia

# **BC856BS** 65 V, 100 mA PNP/PNP general-purpose transistor Rev. 01 — 11 August 2009 Produ

**Product data sheet** 

### 1. Product profile

### 1.1 General description

PNP/PNP general-purpose transistor pair in a very small Surface-Mounted Device (SMD) plastic package.

#### Table 1. **Product overview**

Type number			NPN/NPN	NPN/PNP
	NXP	JEITA	complement	complement
BC856BS	SOT363	SC-88	BC846BS	BC846BPN

### 1.2 Features

- Low collector capacitance
- Low collector-emitter saturation voltage
- Closely matched current gain
- Reduces number of components and board space
- No mutual interference between the transistors
- AEC-Q101 qualified

### **1.3 Applications**

General-purpose switching and amplification

### 1.4 Quick reference data

Table 2.	Quick reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per trans	istor					
$V_{CEO}$	collector-emitter voltage	open base	-	-	-65	V
I <sub>C</sub>	collector current		-	-	-100	mA
h <sub>FE</sub>	DC current gain	$V_{CE} = -5 \text{ V};$ $I_{C} = -2 \text{ mA}$	200	290	450	



### 65 V, 100 mA PNP/PNP general-purpose transistor

## 2. Pinning information

Table 3.	Pinning		
Pin	Description	Simplified outline	Graphic symbol
1	emitter TR1		
2	base TR1		
3	collector TR2		
4	emitter TR2		
5	base TR2		
6	collector TR1		1 2 3
			sym018

# 3. Ordering information

Table 4.       Ordering information				
Type number	Package			
	Name	Description	Version	
BC856BS	SC-88	plastic surface-mounted package; 6 leads	SOT363	

### 4. Marking

Table 5. Marking codes	
Type number	Marking code <sup>[1]</sup>
BC856BS	*E6
BC856BS	*E6

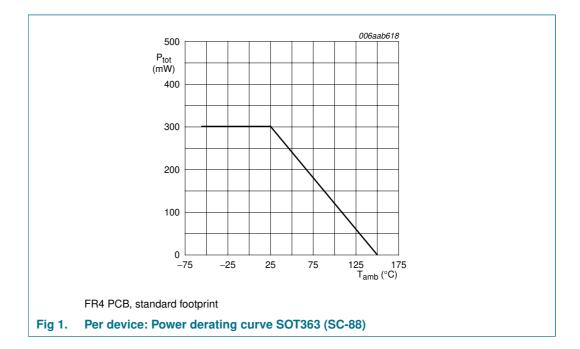
- [1] \* = -: made in Hong Kong
  - \* = p: made in Hong Kong
  - \* = t: made in Malaysia
  - \* = W: made in China

### 65 V, 100 mA PNP/PNP general-purpose transistor

# 5. Limiting values

Table 6. In accorda	Limiting values nce with the Absolute Maxim	um Rating System (	IEC 60134).		
Symbol	Parameter	Conditions	Min	Max	Unit
Per transi	stor				
V <sub>CBO</sub>	collector-base voltage	open emitter	-	-80	V
$V_{\text{CEO}}$	collector-emitter voltage	open base	-	-65	V
$V_{\text{EBO}}$	emitter-base voltage	open collector	-	-6	V
I <sub>C</sub>	collector current		-	-100	mA
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms	-	-200	mA
I <sub>BM</sub>	peak base current	single pulse; t <sub>p</sub> ≤ 1 ms	-	-200	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	[1] -	200	mW
Per device	e				
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	<u>[1]</u> _	300	mW
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-55	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

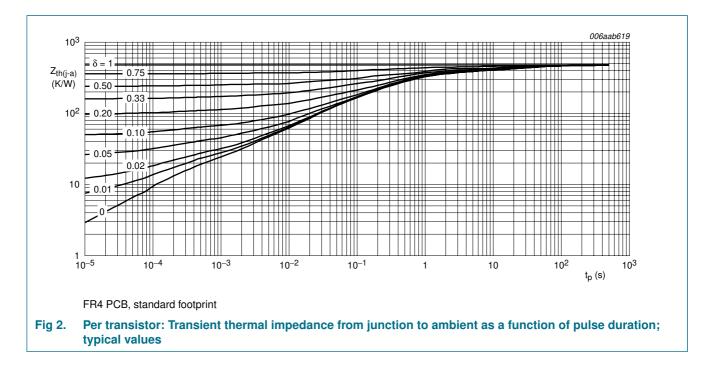


#### 65 V, 100 mA PNP/PNP general-purpose transistor

### 6. Thermal characteristics

Table 7.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per trans	istor					
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	<u>[1]</u> _	-	625	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point		-	-	230	K/W
Per devic	e					
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	<u>[1]</u> -	-	416	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.



### 65 V, 100 mA PNP/PNP general-purpose transistor

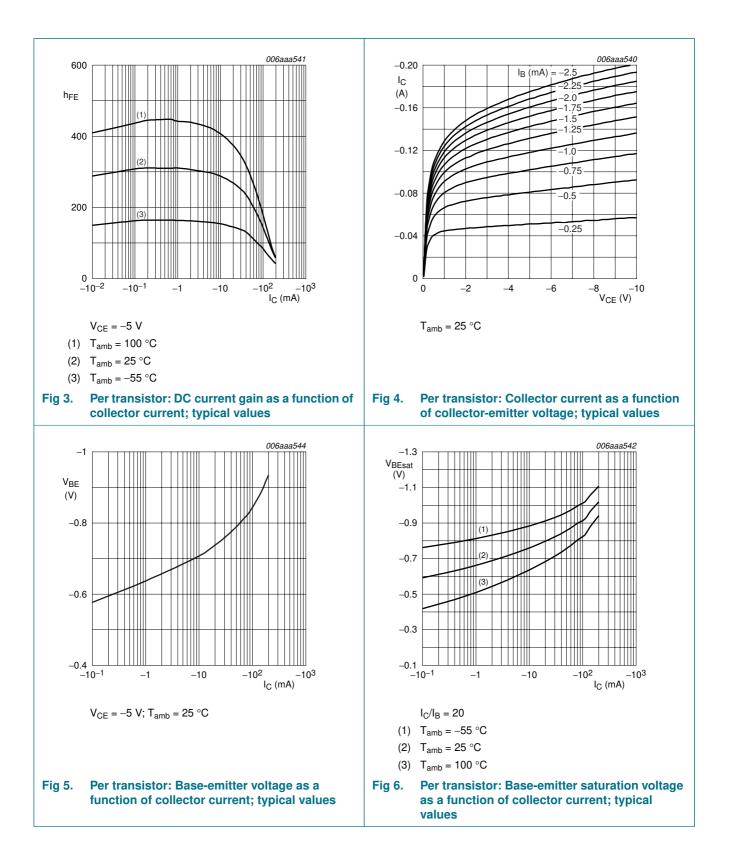
## 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per trans	sistor					
I <sub>CBO</sub>		$V_{CB} = -50 \text{ V}; \text{ I}_{\text{E}} = 0 \text{ A}$	-	-	-15	nA
	current		-	-	-5	μA
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = -6 \text{ V}; \text{ I}_{C} = 0 \text{ A}$	-	-	-100	nA
h <sub>FE</sub>	DC current gain	$V_{CE} = -5 V$				
		$I_C = -10 \ \mu A$	-	270	-	
		$I_{\rm C} = -2  \rm{mA}$	200	290	450	
V <sub>CEsat</sub> collector-emitter saturation voltage		$I_{C} = -10 \text{ mA};$ $I_{B} = -0.5 \text{ mA}$	-	-55	-100	mV
	$I_C = -100 \text{ mA}; I_B = -5 \text{ mA}$	-	-200	-300	mV	
V <sub>BEsat</sub>	BEsat base-emitter saturation voltage	$I_{C} = -10 \text{ mA};$ $I_{B} = -0.5 \text{ mA}$	-	-755	-850	mV
		$I_{\rm C} = -100 \text{ mA}; I_{\rm B} = -5 \text{ mA}$	-	-900	-	mV
V <sub>BE</sub>	base-emitter voltage	$V_{CE} = -5 V$				
		$I_{\rm C} = -2  \rm{mA}$	-600	-650	-750	mV
		$I_{\rm C} = -10 \text{ mA}$	-	-	-820	mV
C <sub>c</sub>	collector capacitance	$V_{CB} = -10 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz	-	2.3	-	рF
C <sub>e</sub>	emitter capacitance	$V_{EB} = -0.5 V;$ $I_{C} = i_{c} = 0 A; f = 1 MHz$	-	10	-	pF
f <sub>T</sub>	transition frequency	$\label{eq:Vce} \begin{array}{l} V_{CE} = -5 \ V; \ I_C = -10 \ mA; \\ f = 100 \ MHz \end{array}$	100	-	-	MHz
NF	NF noise figure		-	1.6	-	dB
		$V_{CE} = -5 \text{ V}; I_C = -0.2 \text{ mA};$ $R_S = 2 \text{ k}\Omega; \text{ f} = 1 \text{ kHz};$ B = 200  Hz	-	2.9	-	dB

### **NXP Semiconductors**

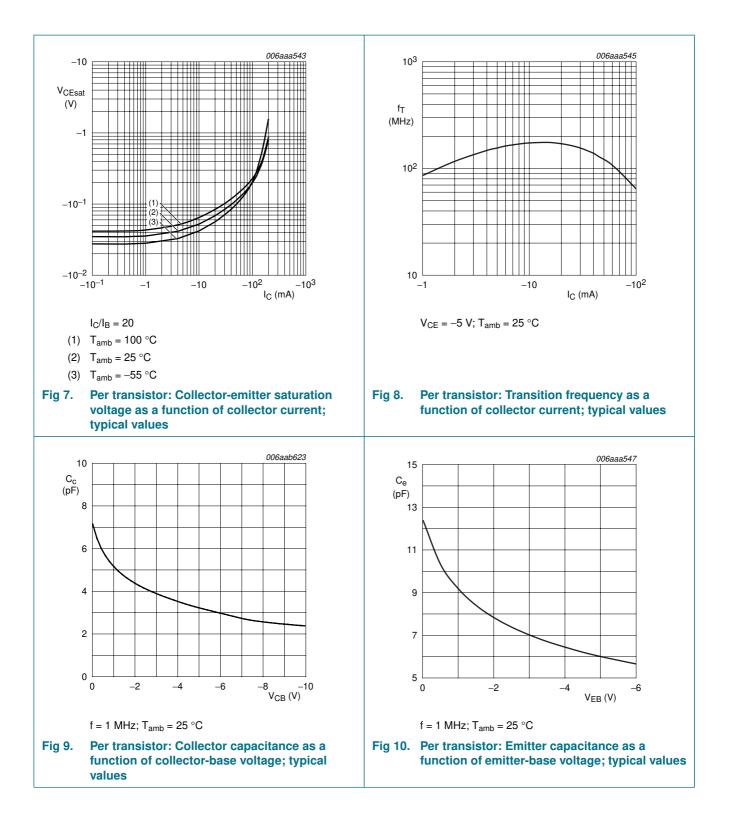
# BC856BS

#### 65 V, 100 mA PNP/PNP general-purpose transistor



BC856BS 1

#### 65 V, 100 mA PNP/PNP general-purpose transistor



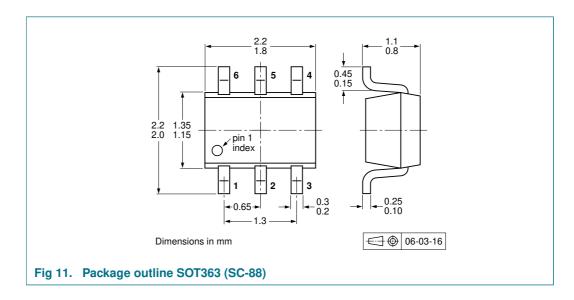
#### 65 V, 100 mA PNP/PNP general-purpose transistor

### 8. Test information

### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

### 9. Package outline



### 10. Packing information

#### Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description I		Packing	g quantity
				3000	10000
BC856BS	SOT363	4 mm pitch, 8 mm tape and reel; T1	[2]	-115	-135
		4 mm pitch, 8 mm tape and reel; T2	<u>[3]</u>	-125	-165

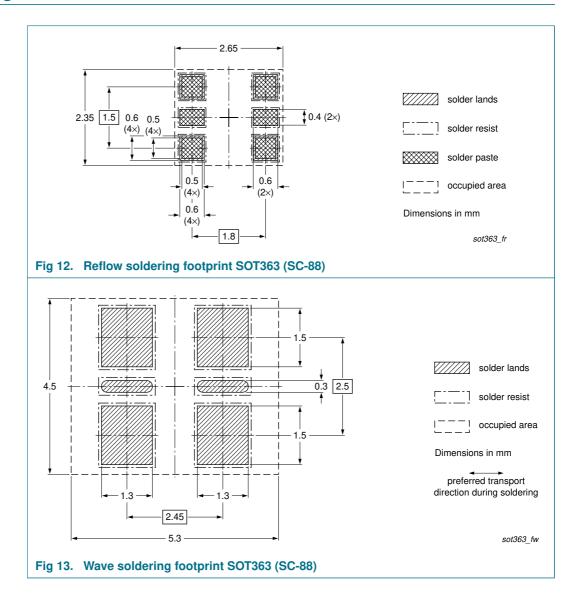
[1] For further information and the availability of packing methods, see Section 14.

[2] T1: normal taping

[3] T2: reverse taping

65 V, 100 mA PNP/PNP general-purpose transistor

### 11. Soldering



### 65 V, 100 mA PNP/PNP general-purpose transistor

# 12. Revision history

Table 10. Revision history				
Document ID	Release date	Data sheet status	Change notice	Supersedes
BC856BS_1	20090811	Product data sheet	-	-

### **13. Legal information**

### 13.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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BC856BS\_1 Product data sheet

#### 65 V, 100 mA PNP/PNP general-purpose transistor

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